

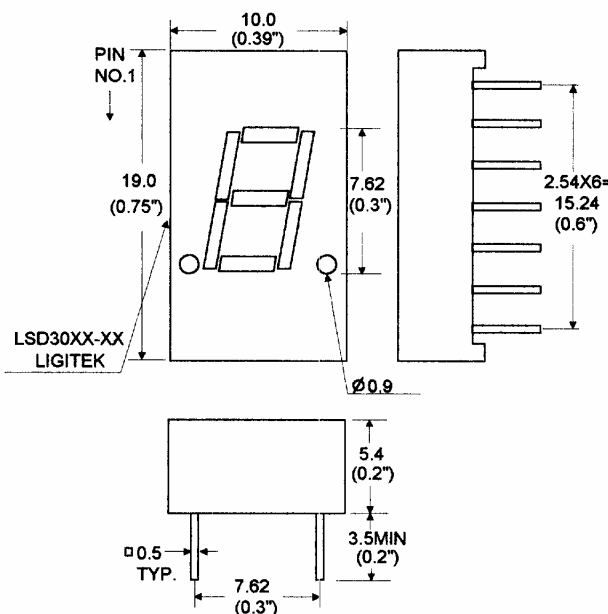
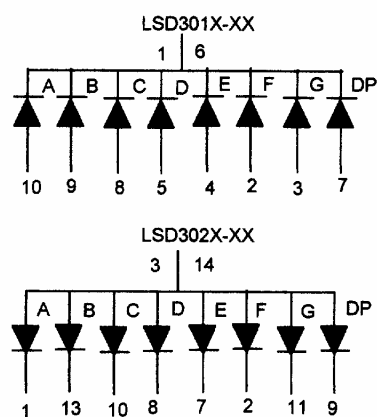
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LIGITEK

SINGLE DIGIT LED DISPLAY (0.3Inch)		LSD301X/2X series		Page 1/2	
PACKAGE DIMENSION		INTERNAL CIRCUIT DIAGRAM			
					
NOTE: All Dimension Are In Millimeters And (Inch) Tolerance Is $\pm 0.25(0.01")$ Unless Otherwise Noted					
• Connection To Electrical Schematic					
Electrical Connection					
PIN NO.		LSD301X-XX		PIN NO.	LSD302X-XX
1		Common Cathode		1	Cathode A
2		Anode F		2	Cathode F
3		Anode G		3	Common Anode
4		Anode E		4	No Pin
5		Anode D		5	No Pin
6		Common Cathode		6	No Connect
7		Anode Dp		7	Cathode E
8		Andoe C		8	Cathode D
9		Anode B		9	Cathode DP
10		Andoe A		10	Cathode C
11				11	Cathode G
12				12	No Pin
13				13	Cathode B
14				14	Common Anode
文件編號: QW0905-S301/2X-XX 版本: A 生效日期: May . 17 . 1996					

• **Part Selection And Application Information (Ratings At 25°C Ambient)**

PART NO	CHIP		common cathode or anode	λ_P (nm)	$\Delta\lambda$ (nm)	Electrical					IV-M
						Vf(v)			Iv(mcd)		
	Material	Emitted				Min	Typ.	Max	Min	Typ.	
LSD3015-XX	GaAlAs	Red	Common Cathode	660	20	1.5	1.7	2.1	0.3	0.5	2:1
LSD3011-XX	GaP	Red		697	90	1.7	1.9	2.2	0.5	0.8	2:1
LSD3012-XX	GaP	Green		565	30	1.7	1.9	2.2	1.2	2.0	2:1
LSD3013-XX	GaAsP/GaP	Yellow		585	35	1.7	1.9	2.2	1.1	1.8	2:1
LSD3014-XX	GaAsP/GaP	Orange		635	45	1.7	1.9	2.2	1.2	2.0	2:1
LSD3025-XX	GaAlAs	Red	Common Anode	660	20	1.5	1.7	2.1	0.3	0.5	2:1
LSD3021-XX	GaP	Red		697	90	1.7	1.9	2.2	0.5	0.8	2:1
LSD3022-XX	GaP	Green		565	30	1.7	1.9	2.2	1.2	2.0	2:1
LSD3023-XX	GaAsP/GaP	Yellow		585	35	1.7	1.9	2.2	1.1	1.8	2:1
LSD3024-XX	GaAsP/GaP	Orange		635	45	1.7	1.9	2.2	1.2	2.0	2:1

• **Absolute Maximum Rating (Ta=25°C)**

Parameter	Red		Green	Yellow		Orange	Unit	Remark
Forward Current Per Chip	SR	H	G	Y		E		
	40	15	30	20		30	mA	
Peak Current Per Chip (Duty 1/10, 0.1MS Pulse Width)	200	60	120	80		120	mA	
Power Dissipation Per Chip	110	45	100	85		100	mW	
Derating Linear From 25°C Per Chip	0.45	0.25	0.45	0.45		0.45	mA/ °C	
Reverse Current Per Any Chip	10		10	10		10	μA	
Operating Temperature	-40°C TO +85°C							
Storage Temperature	-40°C TO +100°C							

Solder Temperature 1/16 Inch Below Seating Plane For 3 Seconds At 260°C

• **Test Condition For Each Parameter**

Parameter	Symbol	Unit	Test Condition
Forward Voltage Per Chip	Vf	volt	If=3mA
Luminous Intensity Per Chip	Iv	mcd	If=3mA
Peak Emission Wavelength	λ_P	nm	If=20mA
Spectral Line Half-Width	$\Delta\lambda$	nm	If=20mA
Reverse Current Any Chip	Ir	μA	Vr=5V
Luminous Intensity Matching Ratio	IV-M		